

C1812H102KGGACTU

Aliases (C1812H102KGGAC7800)

SMD Indust COG HVHT200C, Ceramic, 1000 pF, 10%, 2000 VDC, COG, SMD, MLCC, High Temperature, Ultra-Stable, Low Loss, 1812



Click [here](#) for the 3D model.

General Information	
Series	SMD Indust COG HVHT200C
Style	SMD Chip
Description	SMD, MLCC, High Temperature, Ultra-Stable, Low Loss
Features	High Temp, Ultra-Stable, Low Loss
RoHS	Yes
Termination	Tin
Marking	No
AEC-Q200	No
Component Weight	87 mg
Shelf Life	78 Weeks
MSL	1

Dimensions	
Chip Size	1812
L	4.5mm +/-0.3mm
W	3.2mm +/-0.3mm
T	2mm +/-0.20mm
B	0.6mm +/-0.35mm

Specifications	
Capacitance	1000 pF
Measurement Condition	1 MHz 1.0Vrms
Capacitance Tolerance	10%
Voltage DC	2000 VDC
Dielectric Withstanding Voltage	2400 VDC
Temperature Range	-55/+200°C
Temperature Coefficient	COG
Capacitance Change with Reference to +25°C and 0 VDC Applied (TCC)	30 ppm/C, 1MegaHz 1.0Vrms
Dissipation Factor	0.1% 1 MHz 1.0Vrms
Aging Rate	0% Loss/Decade Hour
Insulation Resistance	100 GOhms

Packaging Specifications	
Packaging	T&R, 180mm, Plastic Tape
Packaging Quantity	500

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